

512M bit Nand Flash VFBGA

Manufacturers	STMicroelectronics, Inc
Package/Case	BGA-63
Product Type	Memory
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for NAND512R3A2DZA6E or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

NAND512R3A2DZA6E is a specific model of NAND flash memory chip manufactured by Micron Technology. Here are some of its features:

Features

- It has a storage capacity of 512 megabytes (MB).
- It uses a NAND flash memory architecture, which allows for fast read and write speeds.
- It uses a 3.3 volt power supply.
- It has a small form factor and is surface-mountable.
- It has a maximum operating temperature range of -40°C to 85°C.

Application

- S34ML04G200TFI000 from Cypress Semiconductor
- MT29F512G08CKCABH6-IT from Micron Technology
- K9GBG08U0M-PCB0 from Samsung Electronics



Related Products



[NAND01GW3B2BN6F](#)

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TSOP-48



[NAND512W3A2BN6E](#)

STMicroelectronics, Inc
TSOP-1-48



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